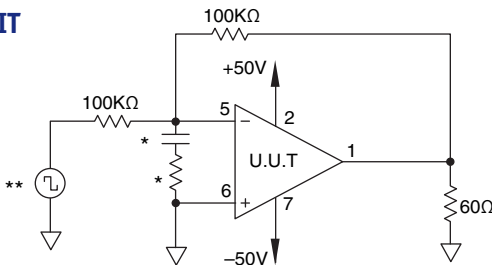


PA84M/883

SG	PARAMETER	SYMBOL	TEMP.	POWER	TEST CONDITIONS	MIN	MAX	UNITS
1	Quiescent Current	I_o	25°C	±150V	$V_{IN} = 0, A_V = 100$		7.5	mA
1	Input Offset Voltage	V_{OS}	25°C	±150V	$V_{IN} = 0, A_V = 100$		3	mV
1	Input Offset Voltage	V_{OS}	25°C	±15V	$V_{IN} = 0, A_V = 100$		5.7	mV
1	Input Bias Current, +IN	$+I_B$	25°C	±150V	$V_{IN} = 0$		50	pA
1	Input Bias Current, -IN	$-I_B$	25°C	±150V	$V_{IN} = 0$		50	pA
1	Input Offset Current	I_{OS}	25°C	±150V	$V_{IN} = 0$		50	pA
3	Quiescent Current	I_o	-55°C	±150V	$V_{IN} = 0, A_V = 100$		9.5	mA
3	Input Offset Voltage	V_{OS}	-55°C	±150V	$V_{IN} = 0, A_V = 100$		5	mV
3	Input Offset Voltage	V_{OS}	-55°C	±15V	$V_{IN} = 0, A_V = 100$		7.7	mV
3	Input Bias Current, +IN	$+I_B$	-55°C	±150V	$V_{IN} = 0$		50	pA
3	Input Bias Current, -IN	$-I_B$	-55°C	±150V	$V_{IN} = 0$		50	pA
3	Input Offset Current	I_{OS}	-55°C	±150V	$V_{IN} = 0$		50	pA
2	Quiescent Current	I_o	125°C	±150V	$V_{IN} = 0, A_V = 100$		9.5	mA
2	Input Offset Voltage	V_{OS}	125°C	±150V	$V_{IN} = 0, A_V = 100$		5.5	mV
2	Input Offset Voltage	V_{OS}	125°C	±15V	$V_{IN} = 0, A_V = 100$		8.2	mV
2	Input Bias Current, +IN	$+I_B$	125°C	±150V	$V_{IN} = 0$		10	nA
2	Input Bias Current, -IN	$-I_B$	125°C	±150V	$V_{IN} = 0$		10	nA
2	Input Offset Current	I_{OS}	125°C	±150V	$V_{IN} = 0$		10	nA
4	Output Voltage, $I_o = 40mA$	V_o	25°C	±47V	$R_L = 1K$	40		V
4	Output Voltage, $I_o = 28.6mA$	V_o	25°C	±150V	$R_L = 5K$	143		V
4	Output Voltage, $I_o = 15mA$	V_o	25°C	±80V	$R_L = 5K$	75		V
4	Current Limits	I_{CL}	25°C	±20V	$R_L = 100\Omega$	36	70	mA
4	Stability/Noise	E_N	25°C	±150V	$R_L = 5K, A_V = 1, C_L = 10nF$		1	mV
4	Slew Rate	SR	25°C	±150V	$R_L = 5K, C_C = 50pF$	100	600	V/ μ s
4	Open Loop Gain	A_{OL}	25°C	±150V	$R_L = 5k, F = 10Hz$	100		dB
4	Common Mode Rejection	CMR	25°C	±32.5V	$R_L = 5k, F = DC, V_{CM} = \pm 22.5V$	90		dB
6	Output Voltage, $I_o = 40mA$	V_o	-55°C	±47V	$R_L = 1K$	40		V
6	Output Voltage, $I_o = 28.6mA$	V_o	-55°C	±150V	$R_L = 5K$	143		V
6	Output Voltage, $I_o = 15mA$	V_o	-55°C	±80V	$R_L = 5K$	75		V
6	Stability/Noise	E_N	-55°C	±150V	$R_L = 5K, A_V = 1, C_L = 10nF$		1	mV
6	Slew Rate	SR	-55°C	±150V	$R_L = 5K, C_C = 50pF$	100	600	V/ μ s
6	Open Loop Gain	A_{OL}	-55°C	±150V	$R_L = 5K, F = 10Hz$	100		dB
6	Common Mode Rejection	CMR	-55°C	±32.5V	$R_L = 5k, F = DC, V_{CM} = \pm 22.5V$	90		dB
5	Output Voltage, $I_o = 30mA$	V_o	125°C	±37V	$R_L = 1K$	30		V
5	Output Voltage, $I_o = 28.6mA$	V_o	125°C	±150V	$R_L = 5K$	143		V
5	Output Voltage, $I_o = 15mA$	V_o	125°C	±80V	$R_L = 5K$	75		V
5	Stability/Noise	E_N	125°C	±150V	$R_L = 5k, A_V = 1, C_L = 10nF$		1	mV
5	Slew Rate	SR	125°C	±150V	$R_L = 5K, C_C = 50pF$	100	600	V/ μ s
5	Open Loop Gain	A_{OL}	125°C	±150V	$R_L = 5K, F = 10Hz$	100		dB
5	Common Mode Rejection	CMR	125°C	±32.5V	$R_L = 5k, F = DC, V_{CM} = \pm 22.5V$	90		dB

BURN IN CIRCUIT



* These components are used to stabilize device due to poor high frequency characteristics of burn in board.

** Input signals are calculated to result in internal power dissipation of approximately 2.1W at case temperature = 125°C.